

# **isc Silicon NPN Power Transistor**

### **DESCRIPTION**

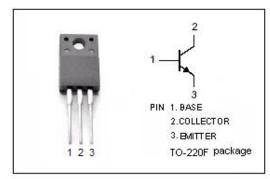
- · Collector-Emitter Breakdown Voltage-
  - : V<sub>(BR)CEO</sub>= 80V(Min)
- DC Current Gain-
- : h<sub>FE</sub>= 40(Min)@ I<sub>C</sub>= 1A
- Complement to Type 2SA1488A
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

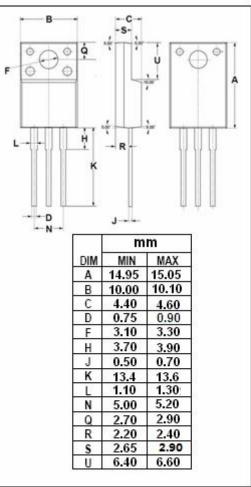


• Designed for audio and general purpose applications.



SYMBOL	PARAMETER	VALUE	UNIT
V <sub>СВО</sub>	Collector-Base Voltage	100	V
V <sub>CEO</sub>	Collector-Emitter Voltage	80	V
V <sub>EBO</sub>	Emitter-Base Voltage	6	V
Ic	Collector Current-Continuous	4	Α
I <sub>B</sub>	Base Current-Continuous	1	Α
Pc	Collector Power Dissipation @T <sub>C</sub> =25℃	25	W
TJ	Junction Temperature	150	$^{\circ}$
T <sub>stg</sub>	Storage Temperature	-55~150	$^{\circ}$







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2SC3851A

### **ELECTRICAL CHARACTERISTICS**

Tj=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT			
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 25mA; I <sub>B</sub> = 0	80			V			
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 2A; I <sub>B</sub> = 0.2A			0.5	V			
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 100V; I <sub>E</sub> = 0			100	μА			
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 6V; I <sub>C</sub> = 0			100	μА			
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 1A; V <sub>CE</sub> = 4V	40		320				
Сов	Output Capacitance	I <sub>E</sub> = 0; V <sub>CB</sub> = 10V; f= 1MHz		60		pF			
f⊤	Current-Gain—Bandwidth Product	I <sub>E</sub> = -0.2A; V <sub>CE</sub> = 12V		15		MHz			
Switching Times									
ton	Turn-On Time			0.2		μ <b>s</b>			
tstg	Storage Time	I <sub>C</sub> = 2A; I <sub>B1</sub> = -I <sub>B2</sub> = 0.2A; V <sub>CC</sub> = 12V; R <sub>L</sub> = 6 Ω		1.0		μS			
t <sub>f</sub>	Fall Time			0.3		μS			

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